

# SPICE Device Model TP0610K Vishay Siliconix

# P-Channel 60-V (D-S) MOSFET

#### **CHARACTERISTICS**

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

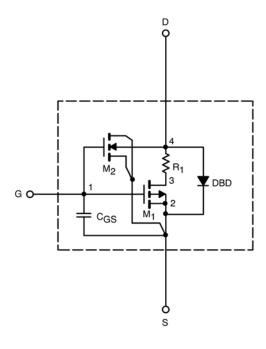
- · Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

#### **DESCRIPTION**

The attached spice model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to  $125^{\circ}$ C temperature ranges under the pulsed 0-V to 10-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{\rm gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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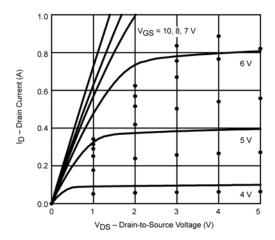
SPECIFICATIONS (T <sub>J</sub> = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static					
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250 \mu A$	2.8		V
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = -10 \text{ V}$	2.2		Α
Drain-Source On-State Resistance <sup>a</sup>	r <sub>DS(on)</sub>	$V_{GS} = -10 \text{ V}, I_D = -500 \text{ mA}$	3	3.1	Ω
		$V_{GS} = -4.5 \text{ V}, I_D = -25 \text{ mA}$	4.4	5.5	
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	$V_{DS} = -10 \text{ V}, I_{D} = -500 \text{ mA}$	170	180	mS
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_{\rm S}$ = -200 mA, $V_{\rm GS}$ = 0 V	-0.75	-0.90	V
Dynamic <sup>b</sup>	-		•	-	
Total Gate Charge	Q <sub>g</sub>	$V_{DS} = -30 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -500 \text{ mA}$	0.50		nC
Gate-Source Charge	$Q_{gs}$		0.12	0.12	
Gate-Drain Charge	$Q_{gd}$		0.14	0.14	

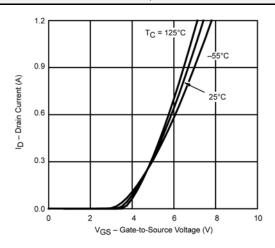
- a. Guaranteed by design, not subject to production testing. b. Pulse test; pulse width  $\leq 300~\mu\text{s},$  duty cycle  $\leq 2\%.$

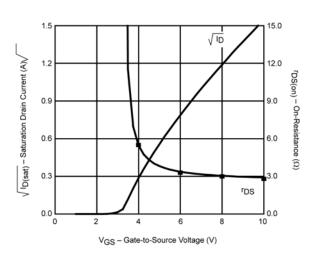


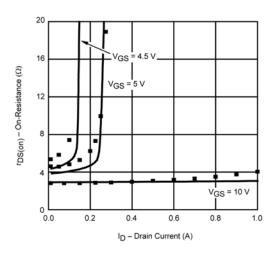
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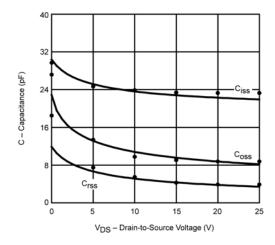
### COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

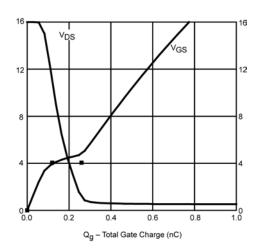












Note: Dots and squares represent measured data.



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